

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE				ATTY. DOCKET NO. I-24016		SERIAL NO. 10/722,643	
<div style="display: flex; align-items: center; justify-content: center;"> <div> INFORMATION DISCLOSURE STATEMENT BY APPLICANT </div> </div>				APPLICANT Alvin D. Compaan et al.			
				FILING DATE November 26, 2003		GROUP Unassigned	

U.S. PATENT DOCUMENTS							
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
JP	4,611,091	Sep. 9, 1986	Choudary et al.				
JP	4,612,411	Sep. 16, 1986	Wieting et al.				
JP	4,798,660	Jan. 17, 1989	Ermer et al.				
JP	4,915,745	Apr. 10, 1990	Pollock et al.				
JP	5,078,804	Jan. 7, 1992	Chen et al.				
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JP	5,436,204	Jul. 25, 1995	Albin et al.				
JP	5,474,939	Dec. 12, 1995	Pollock et al.				
JP	5,909,632	Jun. 1, 1999	Gessert				
JP	6,040,521	Mar. 21, 2000	Kushiya et al.				

FOREIGN PATENT DOCUMENTS							
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO	

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)	
JP	A.N. Tiwari, A. Romeo, D. Baetzner and H. Zogg; Progress in Photovoltaics: Research and Applications; Prog. Photovolt: Res. Appl. 2001; 9:211-215; entitled: "Flexible CdTe Solar Cells on Polymer Films"
JP	G. Gordillo, M. Grizalez, L.C. Moreno and F. Landazabal; Phys. Stat. Sol. (b) 220, 215 (2000) entitled: "Influence of the Optical Window on the Performance of TCO/CdS/CdTe Solar Cells"
JP	L. C. Moreno et al.; Phys. Stat. Sol. (b) 220, 289 (2000); entitled: "pH Effect on the Deposition of CdS on ZnO and SnO ₂ :F Substrates by CBD Method"
JP	Alvin D. Compaan et al.; Annual Technical Report for the Period March, 1998 to March, 1999; Contract No. ZAF-8-17619-14; Dept. of Physics and Astronomy, The University of Toledo; entitled: "High Efficiency Thin Film CdTe and a-Si Based Solar Cells"
JP	A. Romeo et al.; 2 nd World Conference and Exhibition on Photovoltaic Solar Energy Conversion, July, 1998; entitled: "Influence of Transparent Conducting Oxides on the Properties of CdTe/CdS"
JP	J. Han et al.; 1993 American Institute of Physics; Pages 840-842; Appl. Phys. Letter. 62 (8); February 22, 1993; entitled: "Heavy p-doping of ZnTe by Molecular Beam Epitaxy using a Nitrogen Plasma Source"

	DATE CONSIDERED 6/19/05
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